# imall

Chipsmall Limited consists of a professional team with an average of over 10 year of expertise in the distribution of electronic components. Based in Hongkong, we have already established firm and mutual-benefit business relationships with customers from, Europe, America and south Asia, supplying obsolete and hard-to-find components to meet their specific needs.

With the principle of "Quality Parts, Customers Priority, Honest Operation, and Considerate Service", our business mainly focus on the distribution of electronic components. Line cards we deal with include Microchip, ALPS, ROHM, Xilinx, Pulse, ON, Everlight and Freescale. Main products comprise IC, Modules, Potentiometer, IC Socket, Relay, Connector. Our parts cover such applications as commercial, industrial, and automotives areas.

We are looking forward to setting up business relationship with you and hope to provide you with the best service and solution. Let us make a better world for our industry!



# Contact us

Tel: +86-755-8981 8866 Fax: +86-755-8427 6832 Email & Skype: info@chipsmall.com Web: www.chipsmall.com Address: A1208, Overseas Decoration Building, #122 Zhenhua RD., Futian, Shenzhen, China









### **APT2X151DL60J** APT2X150DL60J

600V 150A

Anti-Parallel APT2X150DL60J

Parallel APT2X151DL60J

## Ultrafast Soft Recovery Dual Rectifier Diode

#### PRODUCT APPLICATIONS

- Anti-Parallel Diode -Switchmode Power Supply -Inverters
- Free Wheeling Diode - Motor Controllers - Converters
- Snubber Diode
- Uninterruptible Power Supply
- Induction Heating
- High Speed Rectifiers

#### **PRODUCT FEATURES**

- Ultrafast Recovery Times (trr)
- Soft Recoverery Characteristics 
  Low Noise Switching
- · Low Forward Voltage
- · Low Forward Voltage
- · High Blocking Voltage
- Low Leakage Current

#### **PRODUCT BENEFITS**

- Low Losses
- - Cooler Operation
  - · Higher Reliability Systems
  - Increased System Power Density



**MAXIMUM RATINGS** 

#### All Ratings per Diode: $T_{C}$ = 25°C unless otherwise specified.

Symbol	Characteristic / Test Conditions	Ratings	Unit
V <sub>R</sub>	Maximum D.C. Reverse Voltage		
V <sub>RRM</sub>	Maximum Peak Repetitive Reverse Voltage	600	Volts
V <sub>RWM</sub>	Maximum Working Peak Reverse Voltage		
I <sub>F(AV)</sub>	Maximum Average Forward current (T <sub>c</sub> = 40°C, Duty Cycle = 0.5)	150	
I <sub>F(RMS)</sub>	RMS Forward Currrent (Square wave, 50% duty)	165	Amps
I <sub>FSM</sub>	Non-Repetitive Forward Surge Current (T <sub>J</sub> = 45°C, 8.3 ms)	1000	
T <sub>J</sub> , T <sub>STG</sub>	Operating and Storage Junction Temperature Range	-55 to 175	°C

#### STATIC ELECTRICAL CHARACTERISTICS

Symbol	Characteristic / Test Conditions		Min	Тур	Max	Unit
V <sub>F</sub>	Forward Voltage	I <sub>F</sub> = 150A		1.25	1.6	Volts
		I <sub>F</sub> = 300A		2.0		
		I <sub>F</sub> = 150A, T <sub>J</sub> = 125°C		1.25		
I <sub>RM</sub>	Maximum Reverse Leakage Current	V <sub>R</sub> = 600V			25	μA
		V <sub>R</sub> = 600V, T <sub>J</sub> = 125°C			250	
C <sub>T</sub>	Junction Capacitance, V <sub>R</sub> = 200V			139		pF

1 Continuous current limited by package lead temperature.

#### **DYNAMIC CHARACTERISTICS**

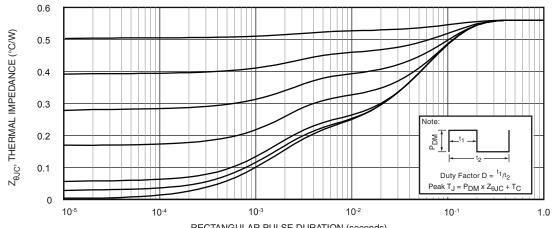
#### APT2X151\_150DL60J

Symbol	Characteristic / Test Conditions		Min	Тур	Max	Unit
t <sub>rr</sub>	Reverse Recovery Time $I_F = 1A$ , $di_F/dt = -15A/\mu s$ , $V_R = 30V$ , $T_J = 25^{\circ}C$			51		20
t <sub>rr</sub>	Reverse Recovery Time	I <sub>F</sub> = 150A, di <sub>F</sub> /dt = -200A/μs V <sub>R</sub> = 400V, T <sub>C</sub> = 25°C		408		ns
Q <sub>rr</sub>	Reverse Recovery Charge			2387		nC
I <sub>RRM</sub>	Maximum Reverse Recovery Current			13		Amps
t <sub>rr</sub>	Reverse Recovery Time	I <sub>F</sub> = 150A, di <sub>F</sub> /dt = -200A/μs V <sub>R</sub> = 400V, T <sub>C</sub> = 125°C		639		ns
Q <sub>rr</sub>	Reverse Recovery Charge			7253		nC
I <sub>RRM</sub>	Maximum Reverse Recovery Current			21		Amps
t <sub>rr</sub>	Reverse Recovery Time	I <sub>F</sub> = 150A, di <sub>F</sub> /dt = -1000A/ μs V <sub>R</sub> = 400V, T <sub>C</sub> = 125°C		299		ns
Q <sub>rr</sub>	Reverse Recovery Charge			12075		nC
I <sub>RRM</sub>	Maximum Reverse Recovery Current			68		Amps

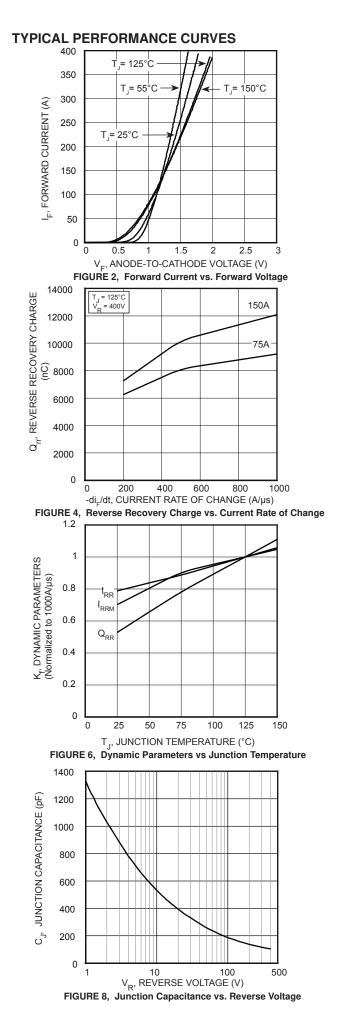
#### THERMAL AND MECHANICAL CHARACTERISTICS

Symbol	Characteristic / Test Conditions	Min	Тур	Max	Unit
R <sub>ejc</sub>	Junction-to-Case Thermal Resistance			0.56	°C/W
V <sub>Isolation</sub>	RMS Voltage (50-60mHz Sinusoidal Waveform from Terminals to Mounting Base for 1 Min.)	2500			
W <sub>T</sub>	Package Weight		1.03		οz
			29.2		g
Torque	Maximum Mounting Torque			10	lb∙in
				1.1	N∙m

Microsemi reserves the right to change, without notice, the specifications and information contained herein.



RECTANGULAR PULSE DURATION (seconds) FIGURE 1. MAXIMUM EFFECTIVE TRANSIENT THERMAL IMPEDANCE, JUNCTION-TO-CASE vs. PULSE DURATION



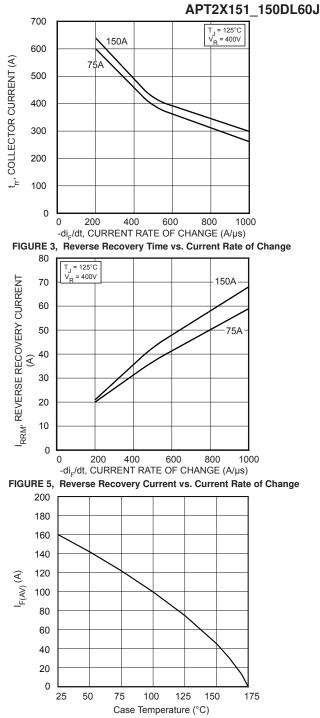


FIGURE 7, Maximum Average Forward Current vs. Case Temperature

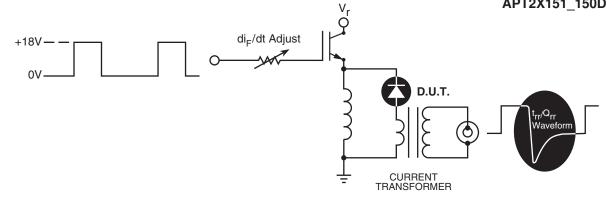
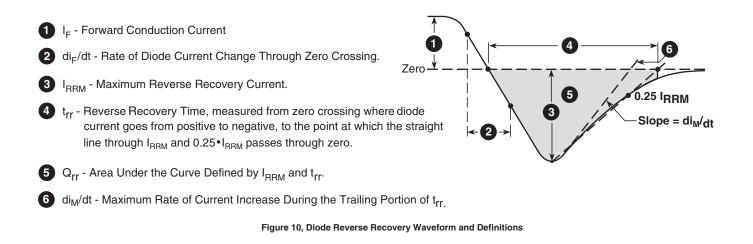
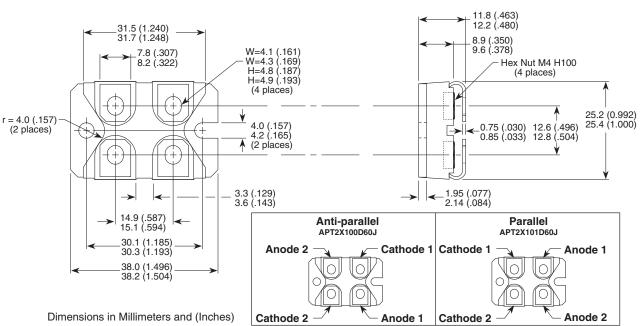


Figure 9. Diode Test Circuit





#### SOT-227 (ISOTOP®) Package Outline